

Si PIN photodiodes

S3071 S3072 S3399

S3883

Large area, high-speed Si PIN photodiodes

The S3071, S3072, S3399 and S3883 are Si PIN photodiodes having a relatively large photosensitive area from ϕ 1.5 to ϕ 5.0 mm yet they offer excellent frequency response from 40 to 300 MHz. These photodiodes are suitable for FSO (free space optics) and high-speed pulsed light detection.

Features

➡ Photosensitive area size

S3071: ф5.0 mm

S3072: \$\phi 3.0 mm

S3399: ф3.0 mm

S3883: **ф1.5** mm

Cutoff frequency S3071: 40 MHz (VR=24 V)

S3072: 45 MHz (VR=24 V)

S3399: 100 MHz (VR=10 V) S3883: 300 MHz (VR=20 V)

➡ High reliability: TO-5/8 metal package

Applications

→ FSO

High-speed pulsed light detection

Structure / Absolute maximum ratings

Type no.	Dimensional outline/ Window material*1	Package		Effortivo	Absolute maximum ratings					
			Photosensitive area size	Effective photosensitive area	Reverse voltage Vr max.	Power dissipation Pd	Operating temperature*2 Topr	Storage temperature* ² Tstg		
			(mm)	(mm ²)	(V)	(mW)	(°C)	(°C)		
S3071	(1)/K	TO-8	ф5.0	19.6	50		-40 to +100	-55 to +125		
S3072	(2)/K		ф3.0	7.0	50	50				
S3399	(3)/K	TO-5	ф3.0	7.0	30	30				
S3883	(4)/K		φ1.5	1.7	30			<u> </u>		

^{*1:} Window material K=borosilicate glass

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

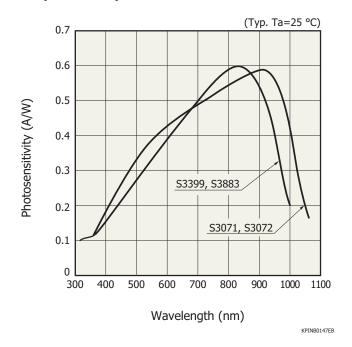
■ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

	•						•				•		
Type no.	Spectral response range	Peak sensitivity wavelength \(\lambda\rho\)		Photosensitivit S (A/W)		ty	Short circuit current Isc	Da curi It	rent	Temp. coefficient of ID	Cutoff frequency fc RL=50 Ω	Terminal capacitance Ct f=1 MHz	Noise equivalent power NEP
			λр	660 nm	780 nm	830 nm	100 lx	(nA)		TCID			λ=λρ
	(nm)	(nm)					(µA)	Typ.	Max.	(times/°C)	(MHz)	(pF)	(W/Hz ^{1/2})
S3071	320 to 1060	920	0.6	0.47	0.54	0.56	17	0.5*3	10*3	1.15	40*3		$2.1 \times 10^{-14 *3}$
S3072							6.5	0.3*3	10*3		45* ³		$1.6 \times 10^{-14 *3}$
S3399	320 to 1000	00 840	0.6	0.45	0.58	0.6	5.6	0.1*4	1.0*4	1.12	100*4		9.4 × 10 ⁻¹⁵ * ⁴
S3883				0.43	0.56		1.4	0.05*5	1.0*5		300*5	6*5	$6.7 \times 10^{-15} * ^{5}$

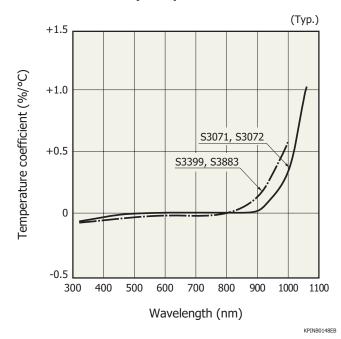
^{*3:} VR=24 V *4: VR=10 V *5: VR=20 V

^{*2:} No condensation

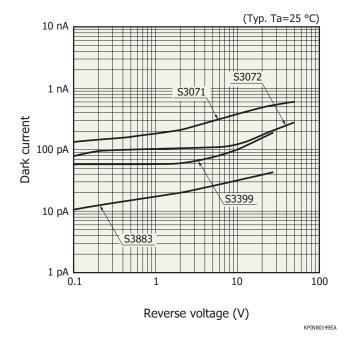
- Spectral response



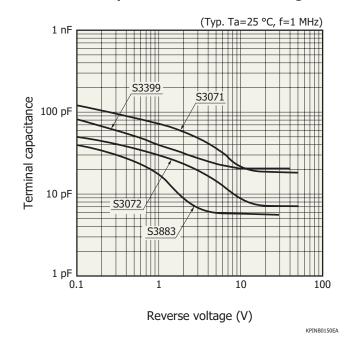
Photosensitivity temperature characteristics



₽ Dark current vs. reverse voltage

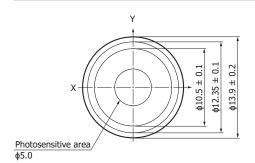


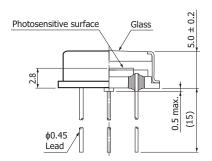
- Terminal capacitance vs. reverse voltage

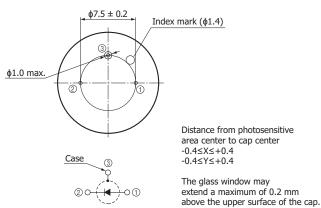


- Dimensional outlines (unit: mm)

(1) S3071

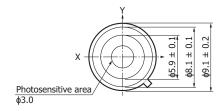


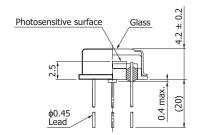


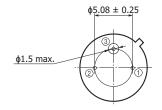


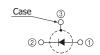
KPINA0027EI

(2) S3072







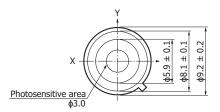


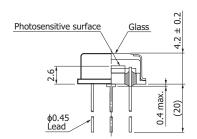
Distance from photosensitive area center to cap center $-0.3 \le X \le +0.3$ $-0.3 \le Y \le +0.3$

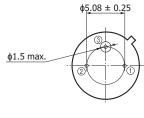
The glass window may extend a maximum of 0.15 mm above the upper surface of the cap.

KPINA0024EC

(3) S3399





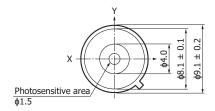


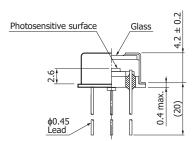
Distance from photosensitive area center to cap center -0.3≤Y≤+0.3

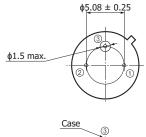


The glass window may extend a maximum of 0.15 mm above the upper surface of the cap.

(4) S3883







Distance from photosensitive area center to cap center -0.3≤X≤+0.3

② · (◄) · ①

KPINA0025FD

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- · Disclaimer
- · Metal, ceramic, plastic package products
- Technical note
- · Si photodiodes

Information described in this material is current as of October, 2022.

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